

Chi-Feng Li

List of Publications by Year in descending order

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2682572

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#	ARTICLE	IF	CITATIONS
1	Experimentally Determining the Top and Edge Contact Resistivities of Two-Step Sulfurization Nb-Doped MoS ₂ Films Using the Transmission Line Measurement. IEEE Electron Device Letters, 2019, 40, 1662-1665.	3.9	7
2	First demonstration of 40-nm channel length top-gate WS ₂ pFET using channel area-selective CVD growth directly on SiO _x /Si substrate. , 2019, , .		22
3	Comparison of Experimentally Extracted Top and Edge Contact Resistivity by TLM Structure with Two-step Sulfurization Nb-Doped MoS ₂ . , 2019, , .		0
4	Demonstration of 40-nm Channel Length Top-Gate p-MOSFET of WS ₂ Channel Directly Grown on SiO _x /Si Substrates Using Area-Selective CVD Technology. IEEE Transactions on Electron Devices, 2019, 66, 5381-5386.	3.0	5